# VTX7S-STR3

# STRATUM-III, high reliable, Temperature compensated (VC)TCXO



Frequency range	5.000 ~ 52.000 MHz			
Standard frequencies	5, 10, 12, 12.8, 13, 15.36, 16, 16.384, 19.2, 19.44, 20 25, 26, 27, 30, 30.72, 32, 40 and 50 MHz			
Frequency stability:	≤ ±4.6 ppm	overall	(Note #1)	
vs. temperature referenced to (FMAX+FMIN)/2	≤ ±0.28 ppm	over -40 to +85 °C	(*)	
Holdover stability	≤ ±0.37 ppm	over 24 hours	(Note #2)	
vs. aging @ +40 °C	≤ ±1.0 ppm	1st year		
Frequency tolerance ex. factory	0 ~ +1.0 ppm	@ +25 °C		
Supply voltage	+2.5 V, +3.3 V or +5.0 V		(*)	
Output signal	Clipped sine wave	CMOS	(*)	
Output level	> 0.8 Vp-p	V <sub>OH</sub> > 0.9*Vcc / \	/ <sub>OL</sub> < 0.1*Vcc	
Output load	10 kΩ // 10 pF	15 pF Max.		
Current consumption, depending on frequency	5 < mA	< 8 mA		
Electronic Frequency Control (EFC)	$\Delta F = \pm 5 \text{ ppm}$	positive slope	(*)	
Control voltage (Vc)	+1.50 V ±1.0 V		(*)	
Tri-state function	pin #9 → high or open pin #9 → low or GND	pin #6 → oscillation pin #6 → high imp		
Phase noise (typical value for 40 MHz)	-90 dBc/Hz -118 dBc/Hz -140 dBc/Hz -151 dBc/Hz -156 dBc/Hz	<ul><li>@ 10 Hz</li><li>@ 100 Hz</li><li>@ 1 kHz</li><li>@ 10 kHz</li><li>@ 100 kHz</li></ul>		
Operating temperature range	-40 ~ +85 °C		(*)	
Storage temperature range	-55 ~ +105 °C			
Reflow Profiles as per IPC/JEDEC J-STD-020C	≤ 260 °C over 10 sec. Max.			
Moisture sensitivity	Level 1 (unlimited)			
(+) Con queilable entires en none #0	Note: Union othornulas on	141 1 1141	@ . OF °C	

### (\*) See available options on page #2

Note: Unless otherwise specified conditions are @+25 °C

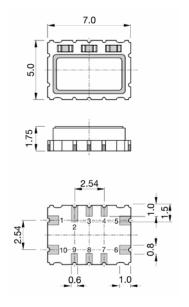
Soldering pattern

0.8

1.27

6.0

Note #1: Including, frequency stability vs. temperature, tolerance @+25°C, aging 20 years, supply & load variation Constant temperature, supply and load change of ±5 % and aging over 24 hours Note #2:



### Pin function

- # 1 Vc (EFC) for VC-TCXO GND or NC for TCXO
- # 5 **GND**
- # 6 Output # 9 Tri-state or NC
- Vcc

Do not contact #2, #3, #4, #7 & #8

#### Test circuit for CMOS Test circuit for Clipped Sine Wave Active probe to Oscilloscope Active probe TRI-STATE to Oscilloscope 0.1 ul VCC VCC 74LVC04 RF-OUTPUT 15 pF GND GND

### 2011/65/EU RoHS compliant

Fax +41 32 644 24 05 Tel +41 32 644 24 00 E-Mail sales@quartzcom.com www.quartzcom.com From design to production in Switzerland

Page 1 of 3

74LVC04 CL

27 Nov. 22

Switzerland 16 VTX7S-STR3 5-52MHz.doc

QuartzCom AG

Bruehlstrasse 15

CH 2540 Grenchen

QuartzCom AG reserves the right to make spec changes to this product

# VTX7S-STR3

# **STRATUM-III**, high reliable, Temperature compensated (VC)TCXO



# **Ordering code**

(0)7S-(1)(2)-(3)(4)-(5)-STR3-40.000MHz Example: TX7S-C33-NNu28-STR3-25.000MHz

Oscillator type	(1) Output signal	(2) Supply voltage	(5) Pulling range (VT only)
TX = TCXO	H = CMOS	25 = 2.5 V	(VI Offiy)
VT = VC-TCXO	C= Clipped sine wave	30 = 3.0 V 33 = 3.3 V	$V05 = 1.5 \pm 1.0 \text{ V } \pm 5 \text{ ppm}$
(3) Operating temperature	(4) Frequency stability		Z = special spec
JK = -20 to +70 °C NN = -40 to +85 °C	$u28 = \pm 0.28 \text{ ppm}$		

## **Environmental conditions**

Test	IEC 60068 Part	IEC 60679-1 Clause	MIL-STD- 202G Method	MIL-STD- 810F Method	MIL-PRF- 55310D Clause	Test conditions (IEC)
Sealing tests (if applicable)	2-17	5.6.2	112E		3.6.1.2	Gross leak: Test Qc, Fine leak: Test Qk
Solderability Resistance to soldering heat	2-20 2-58	5.6.3	208H 210F		3.6.52 3.6.48	Test Ta method 1, Test Td <sub>1</sub> method 2, Test Td <sub>2</sub> method 2
Shock *	2-27	5.6.8	213B Cond C	516.4	3.6.40	Test Ea, 3 x per axis 100 g, 6 ms half-sine pulse
Vibration, sinusoidal*	2-6	5.6.7.1	204D Cond A	516.4-4	3.6.38.1 3.6.38.2	Test Fc, 30 min per axis, 10 Hz – 55 Hz 0,75 mm; 55 Hz – 2 kHz, 10 g
Vibration, random*	2-64	5.6.7.3	214A	514.5	3.6.38.3 3.6.38.4	Test Fdb
Endurance tests - ageing - extended ageing		5.7.1 5.7.2	108A		4.8.35	30 days @ 85 °C 1000 h, 2000 h, 8000 h @ 85 °C

Other environmental conditions on request

QuartzCom AG

Bruehlstrasse 15

CH 2540 Grenchen

Switzerland 16 VTX7S-STR3 5-52MHz.doc 28 Dec. 20

Page 2 of 3 27 Nov. 22

From design to production

in Switzerland

## VTX7S-STR3

**STRATUM-III**, high reliable, Temperature compensated (VC)TCXO



# Handling Recommendation for SMD Crystal & Crystal Oscillator

## 1. ESD Handling

Crystal oscillators are electrostatic sensitive device. Therefore, direct touching of the terminals with fingers and without ESD precautions must be avoid.

Proper handling must be made according to the established ESD handling rules IEC 61340-5-1 and EN 100015-1 to avoid degradations of the oscillator performance due to damages of the internal circuitry by electrostatic discharge.

### 2. Shocks & Vibrations

Excessive mechanical shocks and or vibrations during handling as well as manual and automatic assembly must be avoided.

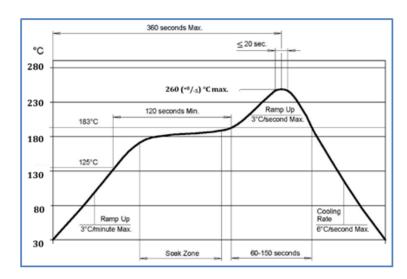
If accidently, the component was dropped or subject to strong shock, component should be verified that the electrical function is still within the specification and still hermetically sealed.

#### 3. Thermal Shocks

Avoid steep temperature gradients. It might lead to breakage of the crystal blank Infrared reflow processes in general are safe.

### 4. Soldering & Cleaning

### Maximum Reflow Condition in accordance with JEDEC STD-020C



Avoid washing or welding processes using Ultrasonic energy. These processes can damage the crystal due to mechanical resonance of the crystal blanks.

### 5. Coating

Using resin may have an impact on the oscillator characteristics.

If resin is used, please contact QuartzCom or our representative for more information.

Fax

Tel

E-Mail

In situations where resin would be used without contacting us in advance,

QuartzCom will not be responsible for any damages caused to the components or and injuries caused to people.

2011/65/EU RoHS compliant

+41 32 644 24 05 +41 32 644 24 00

sales@quartzcom.com

<u>WWW.quartzcom.com</u>

QuartzCom AG reserves the right to make spec changes to this product

